

# BC857BS-QX Datasheet

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DiGi Electronics Part Number	BC857BS-QX-DG
Manufacturer	<a href="#">Nexperia USA Inc.</a>
Manufacturer Product Number	BC857BS-QX
Description	TRANS PNP 45V 0.1A 6TSSOP
Detailed Description	Bipolar (BJT) Transistor Array 2 PNP (Dual) 50V 100mA 100MHz 300mW Surface Mount 6-TSSOP



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## Purchase and inquiry

Manufacturer Product Number:

BC857BS-QX

Series:

-

Transistor Type:

2 PNP (Dual)

Voltage - Collector Emitter Breakdown (Max):

50V

Current - Collector Cutoff (Max):

15nA (ICBO)

Power - Max:

300mW

Operating Temperature:

150°C (TJ)

Qualification:

AEC-Q101

Package / Case:

6-TSSOP, SC-88, SOT-363

Base Product Number:

BC857

Manufacturer:

Nexperia USA Inc.

Product Status:

Active

Current - Collector (Ic) (Max):

100mA

Vce Saturation (Max) @ Ib, Ic:

400mV @ 5mA, 100mA

DC Current Gain (hFE) (Min) @ Ic, Vce:

200 @ 2mA, 5V

Frequency - Transition:

100MHz

Grade:

Automotive

Mounting Type:

Surface Mount

Supplier Device Package:

6-TSSOP

## Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Unaffected

HTSUS:

8541.21.0075

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99



# BC857BS-Q

PNP general purpose double transistor

29 June 2021

Product data sheet

## 1. General description

PNP general-purpose double transistor in a very small SOT363 (SC-88) Surface-Mounted Device (SMD) plastic package. NPN complement: BC847BS-Q.

## 2. Features and benefits

- Low collector capacitance
- Low collector-emitter saturation voltage
- Closely matched current gain
- Reduces number of components and boardspace
- No mutual interference between the transistors
- Qualified according to AEC-Q101 and recommended for use in automotive applications

## 3. Applications

- General purpose switching and amplification.

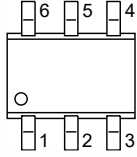
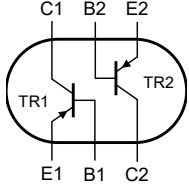
## 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Per transistor</b>						
$V_{CEO}$	collector-emitter voltage	open base	-	-	-45	V
$I_C$	collector current		-	-	-100	mA
$h_{FE}$	DC current gain	$V_{CE} = -5\text{ V}; I_C = -2\text{ mA}; T_{amb} = 25\text{ °C}$	200	-	450	

## 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E1	emitter TR1	 <p>TSSOP6 (SOT363)</p>	 <p>sym138</p>
2	B1	base TR1		
3	C2	collector TR2		
4	E2	emitter TR2		
5	B2	base TR2		
6	C1	collector TR1		

## 6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BC857BS-Q	TSSOP6	plastic, surface-mounted package; 6 leads; 0.65 mm pitch; 2.1 mm x 1.25 mm x 0.95 mm body	SOT363

## 7. Marking

Table 4. Marking codes

Type number	Marking code[1]
BC857BS-Q	3F%

[1] % = placeholder for manufacturing site code

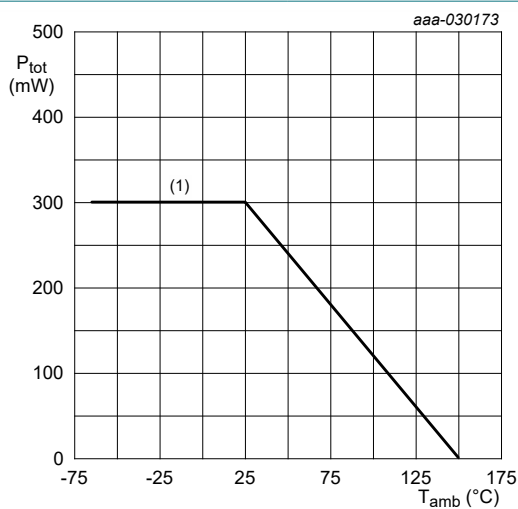
## 8. Limiting values

**Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
<b>Per transistor</b>					
$V_{CBO}$	collector-base voltage	open emitter	-	-50	V
$V_{CEO}$	collector-emitter voltage	open base	-	-45	V
$V_{EBO}$	emitter-base voltage	open collector	-	-5	V
$I_C$	collector current		-	-100	mA
$I_{CM}$	peak collector current	single pulse; $t_p \leq 1$ ms	-	-200	mA
$I_{BM}$	peak base current		-	-200	mA
$P_{tot}$	total power dissipation	$T_{amb} \leq 25$ °C	[1]	200	mW
$T_j$	junction temperature		-	150	°C
$T_{amb}$	ambient temperature		-65	150	°C
$T_{stg}$	storage temperature		-65	150	°C
<b>Per device</b>					
$P_{tot}$	total power dissipation	$T_{amb} \leq 25$ °C	[1]	300	mW

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35  $\mu$ m copper, tin-plated and standard footprint.



(1) FR4 PCB, single-sided, 35  $\mu$ m copper, tin-plated and standard footprint

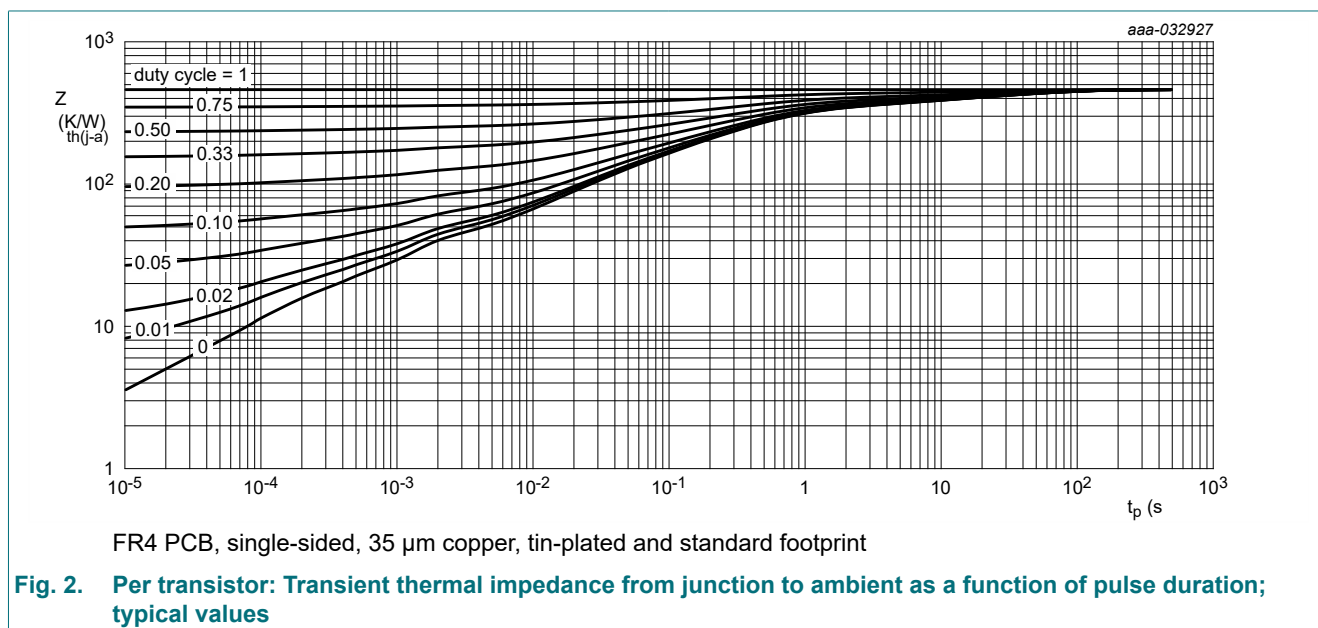
**Fig. 1. Per device: Power derating curves**

## 9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
<b>Per transistor</b>							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	568	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point			-	-	230	K/W
<b>Per device</b>							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	416	K/W

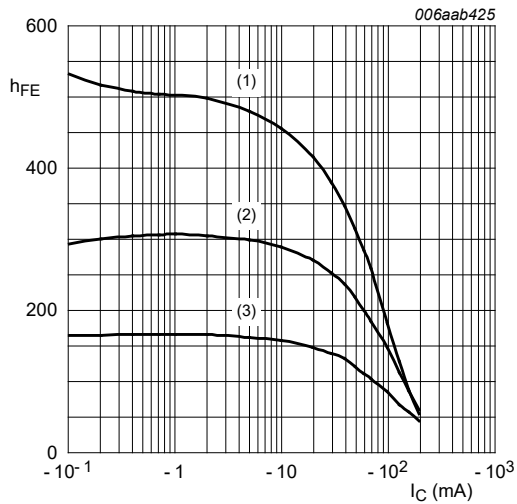
[1] Device mounted on an FR4 PCB, single-sided, 35  $\mu$ m copper, tin-plated and standard footprint.



## 10. Characteristics

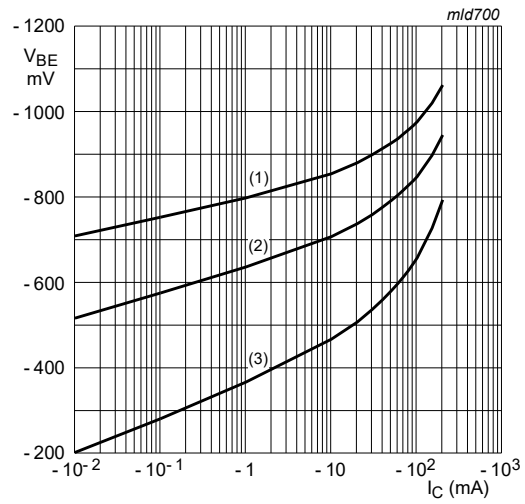
Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Per transistor</b>						
$V_{(BR)CBO}$	collector-base breakdown voltage	$I_C = -100 \mu\text{A}; I_E = 0 \text{ A}; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	50	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = -2 \text{ mA}; I_B = 0 \text{ A}; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	45	-	-	V
$V_{(BR)EBO}$	emitter-base breakdown voltage	$I_C = 0 \text{ A}; I_E = -100 \mu\text{A}; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	5	-	-	V
$I_{CBO}$	collector-base cut-off current	$V_{CB} = -30 \text{ V}; I_E = 0 \text{ A}; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	-15	nA
		$V_{CB} = -30 \text{ V}; I_E = 0 \text{ A}; T_j = 150 \text{ }^\circ\text{C}$	-	-	-5	$\mu\text{A}$
$I_{EBO}$	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_C = 0 \text{ A}; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	-100	nA
$h_{FE}$	DC current gain	$V_{CE} = -5 \text{ V}; I_C = -2 \text{ mA}; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	200	-	450	
$V_{CEsat}$	collector-emitter saturation voltage	$I_C = -10 \text{ mA}; I_B = -0.5 \text{ mA}; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	-100	mV
		$I_C = -100 \text{ mA}; I_B = -5 \text{ mA}; \text{pulsed}; t_p \leq 300 \mu\text{s}; \delta \leq 0.02; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	-400	mV
$V_{BEsat}$	base-emitter saturation voltage	$I_C = -10 \text{ mA}; I_B = -0.5 \text{ mA}; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-755	-	mV
$V_{BE}$	base-emitter voltage	$V_{CE} = -5 \text{ V}; I_C = 2 \text{ mA}; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-600	-655	-750	mV
$C_c$	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = 0 \text{ A}; i_e = 0 \text{ A}; f = 1 \text{ MHz}; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	2.2	pF
$C_e$	emitter capacitance	$V_{EB} = -0.5 \text{ V}; I_C = 0 \text{ A}; i_c = 0 \text{ A}; f = 1 \text{ MHz}; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	10	-	pF
$f_T$	transition frequency	$V_{CE} = -5 \text{ V}; I_C = -10 \text{ mA}; f = 100 \text{ MHz}; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	100	-	-	MHz
NF	noise figure	$V_{CE} = -5 \text{ V}; I_C = -0.2 \text{ mA}; R_S = 2 \text{ k}\Omega; f = 1 \text{ kHz}; B = 200 \text{ Hz}; T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	2	-	dB



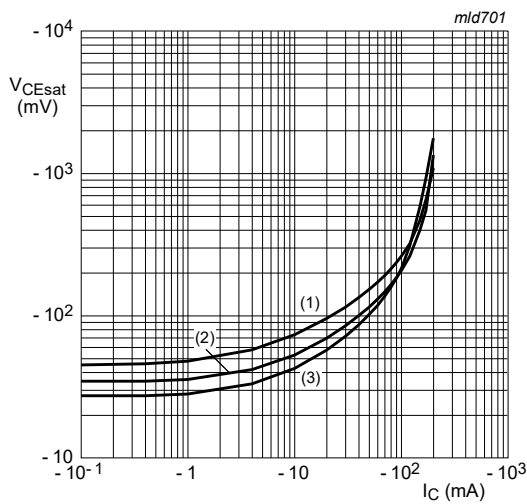
$V_{CE} = -5 \text{ V}$   
 (1)  $T_{amb} = 150 \text{ }^\circ\text{C}$   
 (2)  $T_{amb} = 25 \text{ }^\circ\text{C}$   
 (3)  $T_{amb} = -55 \text{ }^\circ\text{C}$

**Fig. 3. PNP transistor: DC current gain as a function of collector current; typical values**



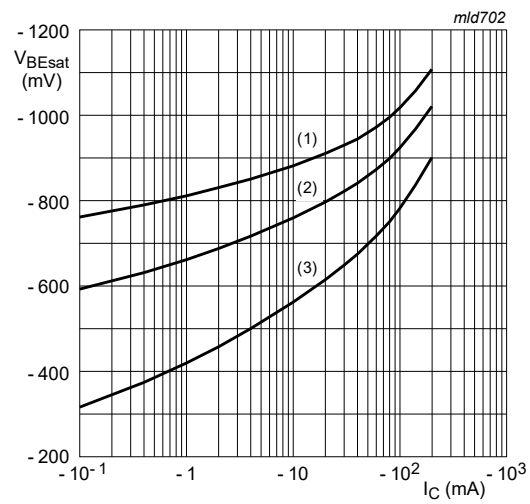
$V_{CE} = -5 \text{ V}$   
 (1)  $T_{amb} = -55 \text{ }^\circ\text{C}$   
 (2)  $T_{amb} = 25 \text{ }^\circ\text{C}$   
 (3)  $T_{amb} = 150 \text{ }^\circ\text{C}$

**Fig. 4. PNP TR2: Base-emitter voltage as a function of collector current; typical values**



$I_C/I_B = 20$   
 (1)  $T_{amb} = 150 \text{ }^\circ\text{C}$   
 (2)  $T_{amb} = 25 \text{ }^\circ\text{C}$   
 (3)  $T_{amb} = -55 \text{ }^\circ\text{C}$

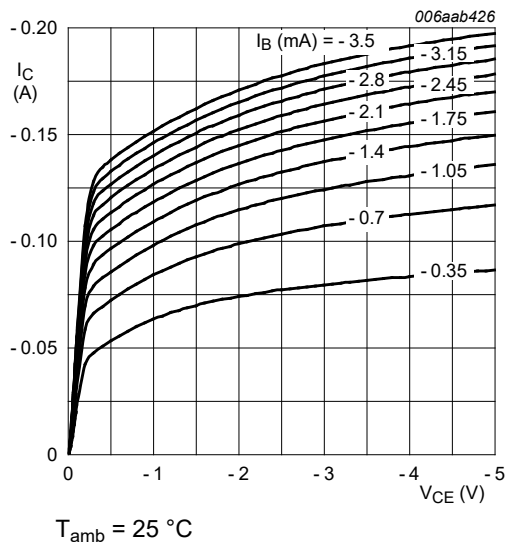
**Fig. 5. PNP TR2: Collector-emitter saturation voltage as a function of collector current; typical values**



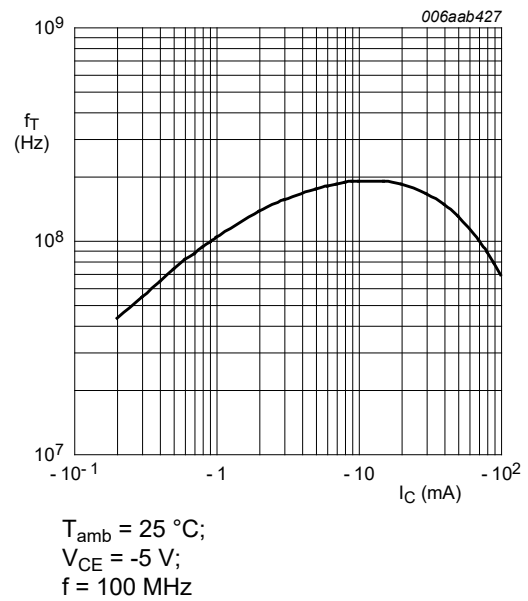
$I_C/I_B = 20$   
 (1)  $T_{amb} = -55 \text{ }^\circ\text{C}$   
 (2)  $T_{amb} = 25 \text{ }^\circ\text{C}$   
 (3)  $T_{amb} = 150 \text{ }^\circ\text{C}$

**Fig. 6. PNP TR2: Base-emitter saturation voltage as a function of collector current; typical values**





**Fig. 7. PNP transistor: Collector current as a function of collector-emitter voltage; typical values**



**Fig. 8. PNP transistor: Transition frequency as a function of collector current; typical values**

## 11. Test information

### Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

## 12. Package outline

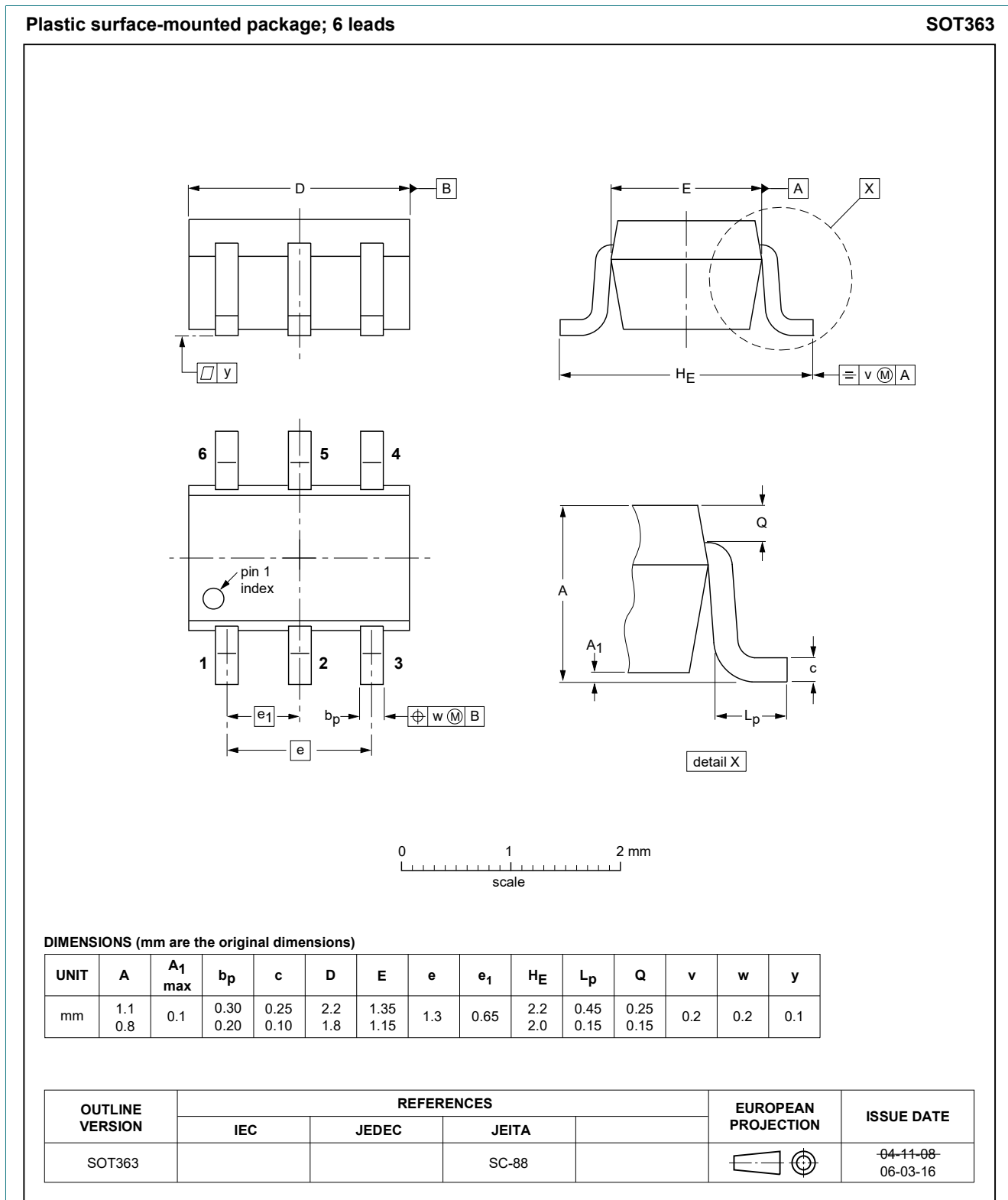


Fig. 9. Package outline TSSOP6 (SOT363)

### 13. Soldering

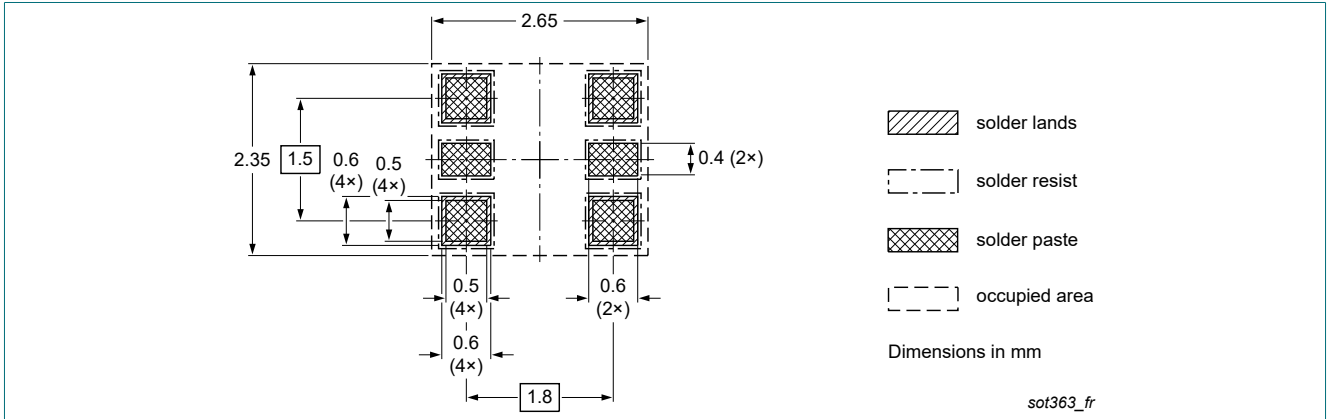


Fig. 10. Reflow soldering footprint for TSSOP6 (SOT363)

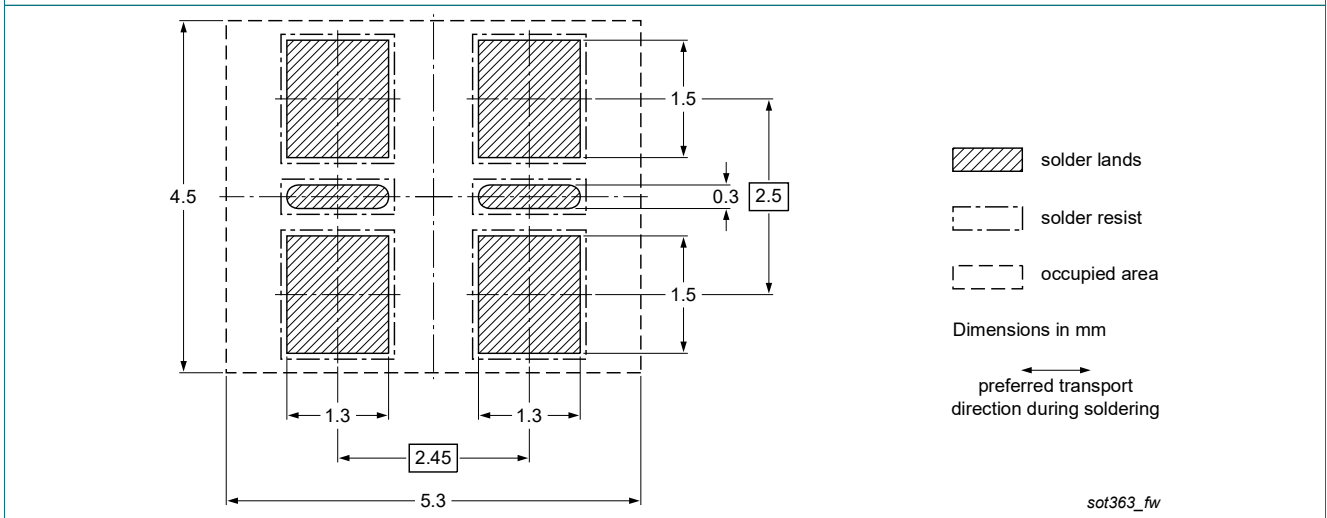


Fig. 11. Wave soldering footprint for TSSOP6 (SOT363)

## 14. Revision history

**Table 8. Revision history**

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BC857BS-Q	20210629	Product data sheet	-	-

## 15. Legal information

### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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## Contents

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1. General description.....	1
2. Features and benefits.....	1
3. Applications.....	1
4. Quick reference data.....	1
5. Pinning information.....	2
6. Ordering information.....	2
7. Marking.....	2
8. Limiting values.....	3
9. Thermal characteristics.....	4
10. Characteristics.....	5
11. Test information.....	7
12. Package outline.....	8
13. Soldering.....	9
14. Revision history.....	10
15. Legal information.....	11

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Date of release: 29 June 2021

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